

# Am29LS18

Quad D Register with Standard and Three-State Outputs

## DISTINCTIVE CHARACTERISTICS

- Low-power Schottky version of the popular Am2918
- Four standard totem-pole outputs
- Four three-state outputs
- Four D-type flip-flops

## GENERAL DESCRIPTION

The Am29LS18 consists of four D-type flip-flops with a buffered common clock. Information meeting the set-up and hold requirements on the D inputs is transferred to the Q outputs on the LOW-to-HIGH transition of the clock.

The same data as on the Q outputs is enabled at the three-state Y outputs when the "output control" ( $\overline{OE}$ ) input is LOW. When the  $\overline{OE}$  input is HIGH, the Y outputs are in the high-impedance state.

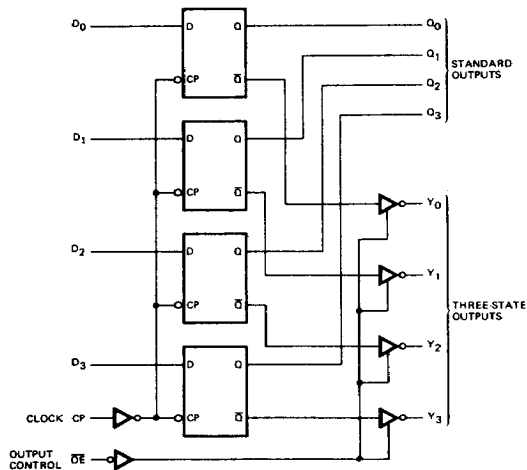
The Am29LS18 is a 4-bit, high-speed register intended for use in real-time signal processing systems where the

standard outputs are used in a recursive algorithm and the three-state outputs provide access to a data bus to dump the results after a number of iterations.

The device can also be used as an address register or status register in computers or computer peripherals.

Likewise, the Am29LS18 is also useful in certain display applications where the standard outputs can be decoded to drive LED's (or equivalent) and the three-state outputs are bus organized for occasional interrogation of the data as displayed.

## BLOCK DIAGRAM



BD002160

## RELATED PRODUCTS

Part No.	Description
Am25S18	Quad D Register
Am25LS2518	Quad D Register
Am25LS2519	Quad Register

03623A

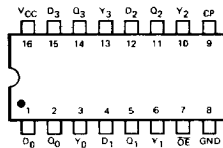
5-160

Refer to Page 13-1 for Essential Information on Military Devices

## CONNECTION DIAGRAM

## Top View

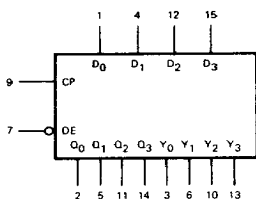
D-16-1



CD004270

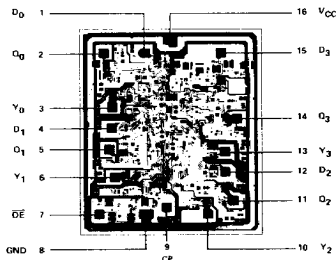
Note: Pin 1 is marked for orientation

## LOGIC SYMBOL



LS000900

## METALLIZATION AND PAD LAYOUT



DIE SIZE 0.083" x 0.099"

## ORDERING INFORMATION

AMD products are available in several packages and operating ranges. The order number is formed by a combination of the following: Device number, speed option (if applicable), package type, operating range and screening option (if desired).

Am29LS18

D

C

B

Screening Option  
Blank - Standard processing  
B - Burn-in

Temperature (See Operating Range)  
C - Commercial (0°C to +70°C)  
M - Military (-55°C to +125°C)

Package

D - 16-pin Cerdip  
F - 16-pin flatpak  
P - 16-pin plastic DIP  
X - Dice

Device type  
Quad D Register

## Valid Combinations

Am29LS18	PC DC, DCB, DM, DMB FM, FMB XC, XM
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## Valid Combinations

Consult the AMD sales office in your area to determine if a device is currently available in the combination you wish.

## PIN DESCRIPTION

Pin No.	Name	I/O	Description
	$D_i$	I	The four data inputs to the register.
	$Q_i$	O	The four data outputs of the register with standard totem-pole active pull-up outputs. Data is passed non-inverted.
	$Y_i$	O	The four three-state data outputs of the register. When the three-state outputs are enabled, data is passed non-inverted. A HIGH on the "output control" input forces the $Y_i$ outputs to the high-impedance state.
9	CP		CP Clock. The buffered common clock for the register. Enters data on the LOW-to-HIGH transition.
7	$\overline{OE}$		$\overline{OE}$ Output Control. When the $\overline{OE}$ input is HIGH, the $Y_i$ outputs are in the high-impedance state. When the $\overline{OE}$ input is LOW, the TRUE register data is present at the $Y_i$ outputs.

## FUNCTION TABLE

INPUTS			OUTPUTS		NOTES
$\overline{OE}$	CLOCK CP	D	Q	Y	
H	L	X	NC	Z	-
H	H	X	NC	Z	-
H	↑	L	L	Z	-
H	↑	H	H	Z	-
L	↑	L	L	L	-
L	↑	H	H	H	-
L	-	-	L	L	1
L	-	-	H	H	1

L = LOW

NC = No change

H = HIGH

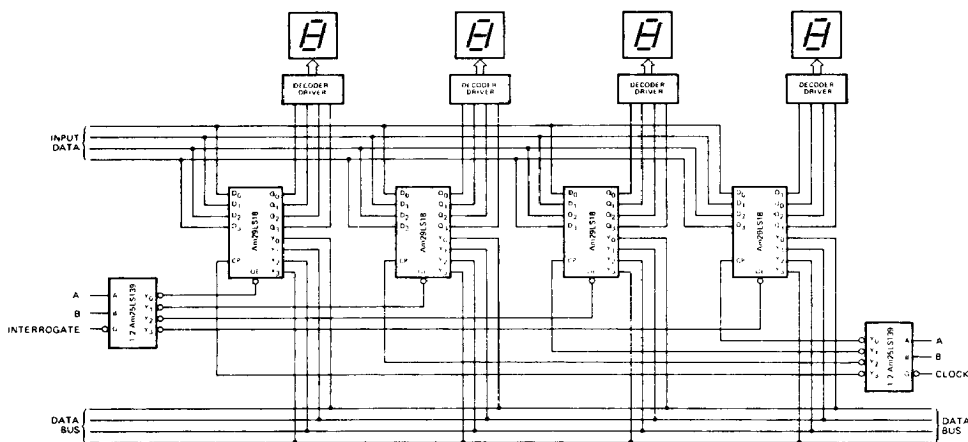
↑ = LOW to HIGH transition

X = Don't care

Z = High impedance

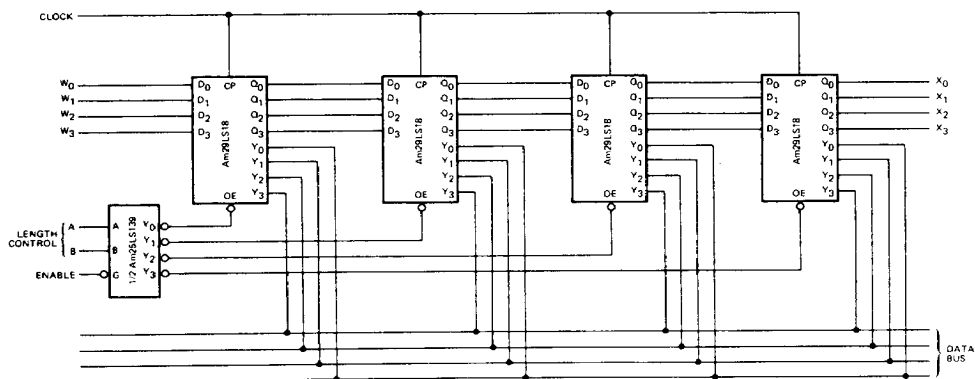
Note: 1. When  $\overline{OE}$  is LOW, the Y output will be in the same logic state as the Q output.

## APPLICATIONS



AF001410

The Am29LS18 used as a display register with bus interrogate capability.



AF001400

The Am29LS18 as a variable length (1, 2, 3 or 4 word) shift register.

**ABSOLUTE MAXIMUM RATINGS**

Storage Temperature ..... -65°C to +150°C  
 (Ambient) Temperature Under Bias ..... -55°C to +125°C  
 Supply Voltage to Ground Potential  
   Continuous ..... -0.5V to +7.0V  
 DC Voltage Applied to Outputs For  
   High Output State ..... -0.5V to +V<sub>CC</sub> max  
 DC Input Voltage ..... -0.5V to +7.0V  
 DC Output Current, Into Outputs ..... 30mA  
 DC Input Current ..... -30mA to +5.0mA

*Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.*

**OPERATING RANGES****Commercial (C) Devices**

Temperature ..... 0°C to +70°C  
 Supply Voltage ..... +4.75V to +5.25V

**Military (M) Devices**

Temperature ..... -55°C to +125°C  
 Supply Voltage ..... +4.5V to +5.5V

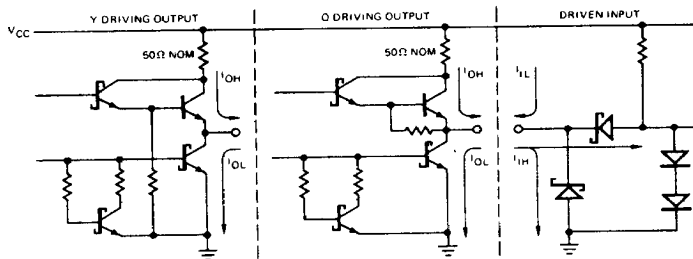
*Operating ranges define those limits over which the functionality of the device is guaranteed.*

**DC CHARACTERISTICS** over operating range unless otherwise specified

Parameters	Description	Test Conditions (Note 2)		Min	Typ (Note 1)	Max	Units
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> = MIN V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	Q, I <sub>OH</sub> = -660μA	MIL	2.5	3.4	Volts
				COM'L	2.7	3.4	
		Y	MIL, I <sub>OH</sub> = -1.0mA		2.4	3.4	
			COM'L, I <sub>OH</sub> = 2.6mA		2.4	3.4	
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> = MIN V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 4.0mA			0.4	Volts
			I <sub>OL</sub> = 8.0mA			0.45	
			I <sub>OL</sub> = 12mA			0.5	
V <sub>IH</sub>	Input HIGH Level	Guaranteed input logical HIGH voltage for all inputs		2.0			Volts
V <sub>IL</sub>	Input LOW Level	Guaranteed input logical LOW voltage for all inputs	MIL			0.7	Volts
			COM'L			0.8	
V <sub>I</sub>	Input Clamp Voltage	V <sub>CC</sub> = MIN, I <sub>IN</sub> = -18mA				-1.5	Volts
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4V				-0.36	mA
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 2.7V				20	μA
I <sub>I</sub>	Input HIGH Current	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0V				0.1	mA
I <sub>O</sub>	Off-State (High-Impedance) Output Current	V <sub>CC</sub> = MAX	V <sub>O</sub> = 0.4V			-20	μA
			V <sub>O</sub> = 2.4V			20	
I <sub>SC</sub>	Output Short Circuit Current (Note 3)	V <sub>CC</sub> = MAX		-15		-85	mA
i <sub>CC</sub>	Power Supply Current (Note 4)	V <sub>CC</sub> = MAX			17	28	mA

- Notes: 1. Typical limits are at V<sub>CC</sub> = 5.0V, 25°C ambient and maximum loading.  
 2. For conditions shown as MIN or MAX, use the appropriate value specified under Operating Ranges for the applicable device type.  
 3. Not more than one output should be shorted at a time. Duration of the short circuit test should not exceed one second.  
 4. I<sub>CC</sub> is measured with all inputs at 4.5V and all outputs open.

# LOW-POWER SCHOTTKY INPUT/OUTPUT CURRENT INTERFACE CONDITIONS



IC000420

Note: Actual current flow direction shown.

## SWITCHING CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ , $V_{CC} = 5.0\text{V}$ )

Parameters	Description	Test Conditions	Min	Typ	Max	Units
$t_{PLH}$	Clock to $Q_i$	$C_L = 15\text{ pF}$ $R_L = 2.0\text{ k}\Omega$		18	27	ns
$t_{PHL}$				18	27	
$t_{PLH}$	Clock to $Y_i$ ( $\overline{OE}$ LOW)			18	27	ns
$t_{PHL}$				18	27	
$t_{pw}$	Clock Pulse Width		18			ns
			15			
$t_s$	Data	$C_L = 5.0\text{ pF}$ $R_L = 2.0\text{ k}\Omega$	15			ns
$t_h$	Data		5.0			
$t_{ZH}$	$\overline{OE}$ to $Y_i$			7.0	11	ns
$t_{ZL}$				8	12	
$t_{HZ}$	$\overline{OE}$ to $Y_i$			14	21	ns
$t_{LZ}$				12	18	
$f_{max}$	Maximum Clock Frequency (Note 1)		35	50		MHz

Note 1. Per industry convention,  $f_{max}$  is the worst case value of the maximum device operating frequency with no constraints on  $t_r$ ,  $t_f$ , pulse width or duty cycle.

## SWITCHING CHARACTERISTICS over operating range unless otherwise specified\*

Parameters	Description		Test Conditions	COMMERCIAL		MILITARY		Units
				Am29LS18		Am29LS18		
				Min	Max	Min	Max	
tPLH	Clock to Qi		CL = 50 pF RL = 2.0 kΩ		38		45	ns
tPHL					38		45	
tPLH	Clock to Yi (OE LOW)				35		40	ns
tPHL					35		40	
tpw	Clock Pulse Width	LOW		20		20	ns	
		HIGH		20		20		
ts	Data			15		15	ns	
th	Data			5.0		5.0	ns	
tZH	OE to Yi				15		17	ns
tZL					16		17	
tHZ	OE to Yi	CL = 50 pF RL = 2.0 kΩ		27		30	ns	
tLZ					24			30
fmax	Maximum Clock Frequency (Note 1)			30		25		MHz

\*AC performance over the operating temperature range is guaranteed by testing defined in Group A, Subgroup 9.

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